Complex Dielectric Function via the Kramers-Kronig Analysis in the Valence Electron Energy-Loss spectrum for ZnTiO₃.

Juan Pantoja-Espinoza¹, G. Herrera-Perez¹, Carlos Ornelas-Gutiérrez², Jesus Uribe-Chavira³, Miguel Meléndez-Zaragoza¹, Jesus Salinas-Gutiérrez³, Alejandro López-Ortiz³ and Virginia Collins-Martínez³

¹Centro de Investigación en Materiales Avanzados, Chihuahua, Chihuahua, Mexico, ²Centro de Investigación en Materiales Avanzados, ³Centro de Investigación en Materiales Avanzados, United States

Electron energy-loss spectroscopy (EELS) is one of the most important techniques to elucidate the local electronic structure of materials. It has the advantage of covering the complete energy range, including valence inter-band transitions in the low energy-loss region, (VEELS); and core level (CEELS) excitations also known as energy-loss near-edge structure (ELNES) [1]. VEELS in a scanning transmission electron microscopy (STEM) mode also provides information about the bandgap energy Eg, and complex dielectric function. However, the VEELS-STEM analysis for perovskite zinc titanate (ZnTiO₃) with hexagonal phase has been rarely reported. This material is frequently used for optoelectronic and photocatalytic applications. The motivation of this work is to determine the bandgap energy Eg and to present the complex dielectric function for perovskite ZnTiO₃ prepared by the Pechini method using the Kramers-Kronig analysis in the VEELS.

ZnTiO₃ was prepared by the Pechini method, the experimental details were reported elsewhere [2]. EELS spectra were obtained with an electron energy loss spectrometer (EELS GAT-777 STEMpack) attached to a JEM-2200FS (200 kV), which offers an energy resolution of 1.0 eV. The electron probe size was below 1 nm. The spectra were acquired using a dispersion of 0.05 eV/channel to record spectra up to 1000 eV. The convergence semi-angle was α = 9.0 mrad for a 2.5 mm spectrometer entrance aperture and 40 mm camera length, and the corresponding collection semi-angle was β = 17.3 mrad. The deconvolution of the zero-loss peak from the VEELS region, the Fourier-log method to remove plural scattering, and Kramers–Kronig analysis were carried out using the Gatan Suite software [3]. Figure 1a shows the VEELS region where the zero-loss peak (ZLP) is identified and elemental analysis is performed for the ZnTiO₃ that exhibits a hexagonal phase. Panel b shows the ELNES for the Ti L₂,3 edge identifying the split into t₂g and eg orbitals due to the crystal field effects [3]. Panel c shows the bright-field STEM micrograph for ZnTiO₃ morphology that exhibits particles with polygonal-shape. Subsequently, the ZLP was deconvoluted in the VEELS region considering in the fit the sum of a single Gaussian and a Lorentzian function squared [3]. The inelastic contribution spectrum was corrected for multiple scattering events using the Fourier-log method (see Figure. 2a) obtaining the single scattering distribution (SSD) [3]. It can be noticed that the bulk plasmon is located at 25.2 eV. The polynomial fit up to the x-axis in the energy loss function (ELF) suggest an electronic bandgap (Eg) of 3.1 eV (panel b). Panel c exhibits the complex dielectric function, ε₁ and ε₂. These curves were obtained through the Kramers-Kronig analysis [3].

It is demonstrated that the VEELS-STEM characterization combined with Kramers–Kronig analysis is a very useful technique to determine the electronic bandgap energy, Eg and to elucidate the complex dielectric function for perovskite ZnTiO₃.

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Figure 1. (a) Elemental identification in the VEELS region. (b) Ti L2,3-edge in the CEELS region. (c) Bright-field micrograph in STEM mode for perovskite ZnTiO$_3$.

Figure 2. (a) Deconvolution of ZLP, inelastic contribution and SSD. (b) Polynomial fit in the ELF to determine the bandgap energy, $E_g$. (c) Complex dielectric function and ELF for ZnTiO$_3$.

References